To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

MOS FIELD EFFECT TRANSISTOR

μPA1724

SWITCHING
N-CHANNEL POWER MOS FET
INDUSTRIAL USE

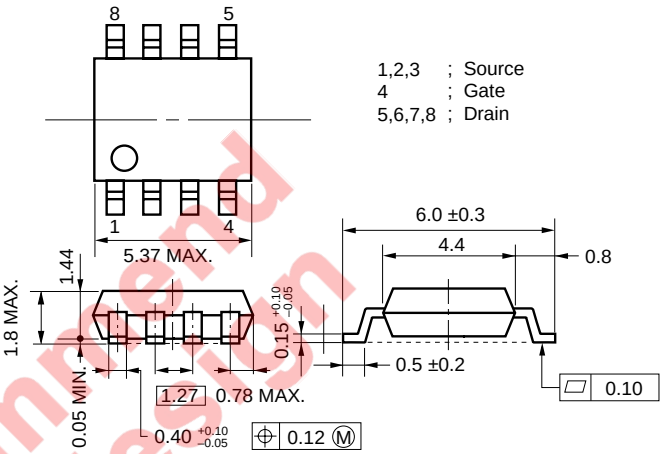
★ DESCRIPTION

The μPA1724 is N-Channel MOS Field Effect Transistor designed for power management applications of notebook computers and so on.

FEATURES

- 2.5-V gate drive and low on-resistance
  $R_{DS(on)1}$ = 11.0 mΩ MAX. (V_{GS} = 4.5 V, I_D = 5.0 A)
- ★ $R_{DS(on)2}$ = 12.0 mΩ MAX. (V_{GS} = 4.0 V, I_D = 5.0 A)
  $R_{DS(on)3}$ = 15.0 mΩ MAX. (V_{GS} = 2.5 V, I_D = 5.0 A)
- Low C_{iss}: C_{iss} = 1850 pF TYP.
- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

PACKAGE DRAWING (Unit : mm)



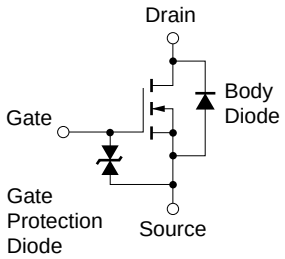
ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA1724G	Power SOP8

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, All terminals are connected.)

Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	20	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	±12	V
Drain Current (DC)	$I_{D(DC)}$	±10	A
Drain Current (pulse) Note1	$I_{D(pulse)}$	±40	A
Total Power Dissipation (T_A = 25°C) Note2	P_T	2.0	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	–55 to +150	°C

EQUIVALENT CIRCUIT



Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1 %

2. Mounted on ceramic substrate of 1200 mm^2 x 2.2 mm

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

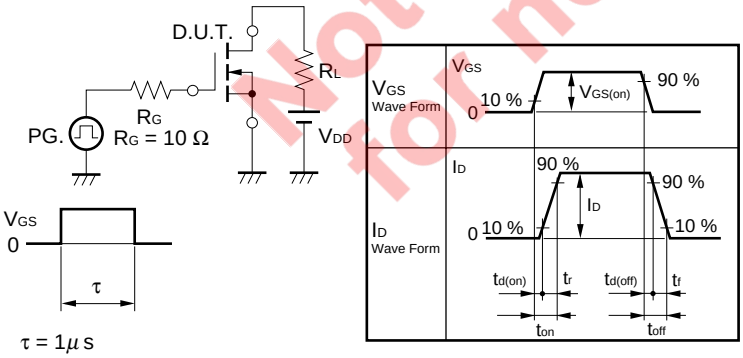
Document No. G14048EJ1V0DS00 (1st edition)
Date Published January 2000 NS CP(K)
Printed in Japan

The mark ★ shows major revised points.

ELECTRICAL CHARACTERISTICS (T_A = 25 °C, All terminals are connected.)

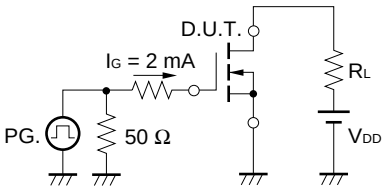
	CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Drain to Source On-state Resistance	$R_{DS(on)1}$	V_{GS} = 4.5 V, I_D = 5.0 A		8.6	11.0	mΩ
★		$R_{DS(on)2}$	V_{GS} = 4.0 V, I_D = 5.0 A		8.8	12.0	mΩ
		$R_{DS(on)3}$	V_{GS} = 2.5 V, I_D = 5.0 A		11.0	15.0	mΩ
	Gate to Source Cut-off Voltage	$V_{GS(off)}$	V_{DS} = 10 V, I_D = 1 mA	0.5	0.84	1.5	V
	Forward Transfer Admittance	$\|y_{fs}\|$	V_{DS} = 10 V, I_D = 5.0 A	10.0	19		S
	Drain Leakage Current	I_{DSS}	V_{DS} = 20 V, V_{GS} = 0 V			10	μA
	Gate to Source Leakage Current	I_{GSS}	V_{GS} = ±12 V, V_{DS} = 0 V			±10	μA
	Input Capacitance	C_{iss}	V_{DS} = 10 V		1850		pF
	Output Capacitance	C_{oss}	V_{GS} = 0 V		610		pF
	Reverse Transfer Capacitance	C_{rss}	f = 1 MHz		320		pF
	Turn-on Delay Time	$t_{d(on)}$	I_D = 5.0 A		43		ns
	Rise Time	t_r	$V_{GS(on)}$ = 4.5 V		170		ns
	Turn-off Delay Time	$t_{d(off)}$	V_{DD} = 10 V		90		ns
	Fall Time	t_f	R_G = 10 Ω		130		ns
	Total Gate Charge	Q_G	I_D = 10 A		18		nC
★	Gate to Source Charge	Q_{GS}	V_{DD} = 16 V		3.2		nC
★	Gate to Drain Charge	Q_{GD}	V_{GS} = 4.5 V		7.8		nC
	Body Diode Forward Voltage	$V_{F(S-D)}$	I_F = 10 A, V_{GS} = 0 V		0.78		V
	Reverse Recovery Time	t_{rr}	I_F = 10 A, V_{GS} = 0 V		45		ns
	Reverse Recovery Charge	Q_{rr}	di/dt = 100 A / μs		40		nC

TEST CIRCUIT 1 SWITCHING TIME



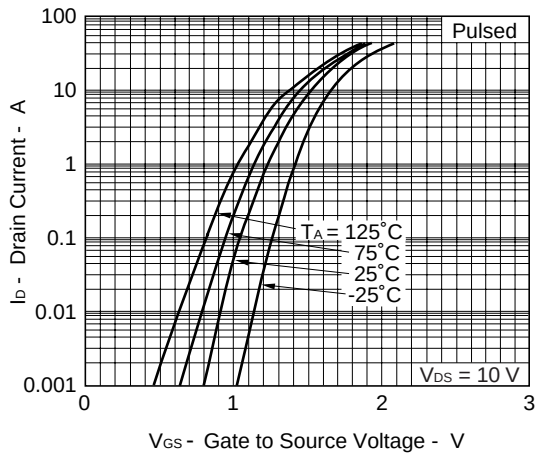
τ = 1μs
Duty Cycle ≤ 1 %

TEST CIRCUIT 2 GATE CHARGE

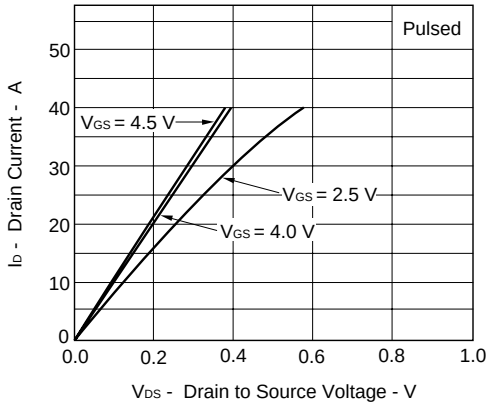


★ TYPICAL CHARACTERISTICS (T_A = 25 °C)

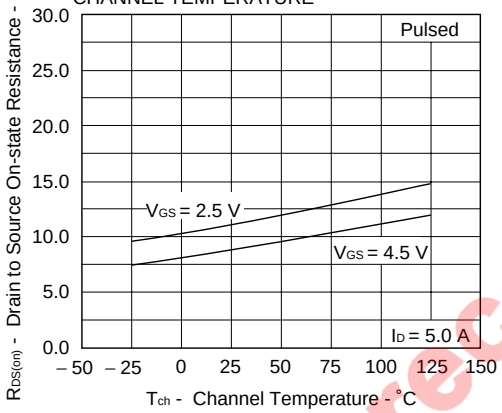
FORWARD TRANSFER CHARACTERISTICS



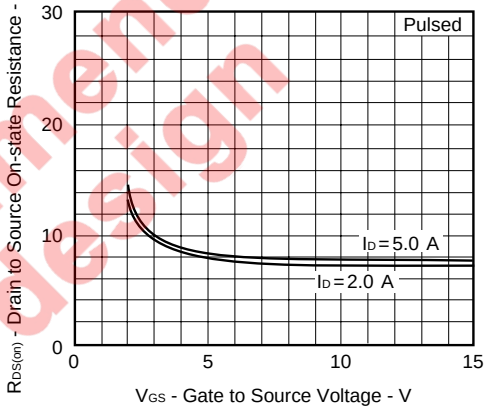
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



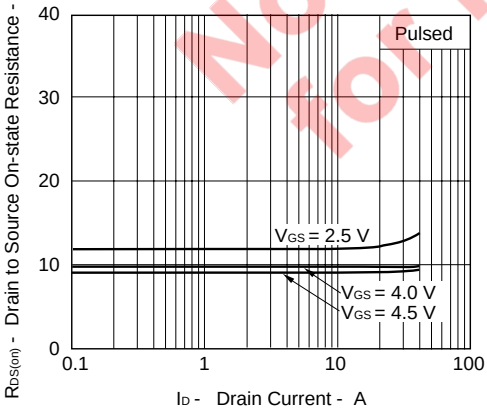
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
CHANNEL TEMPERATURE



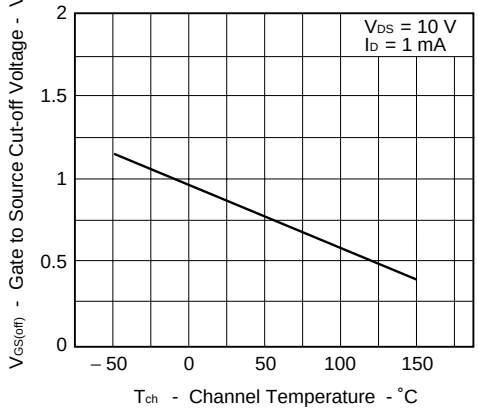
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE



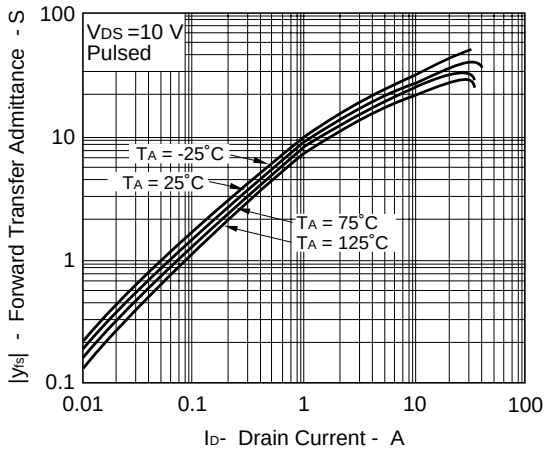
DRAIN TO SOURCE ON-STATE
RESISTANCE vs. DRAIN CURRENT



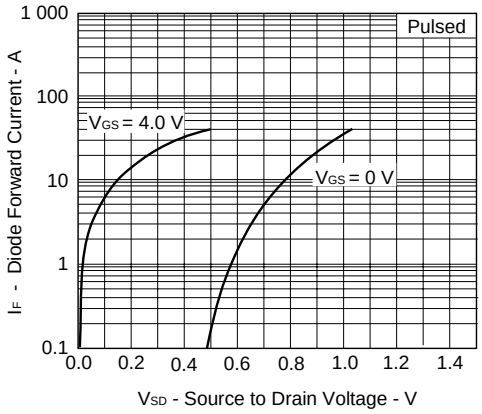
GATE TO SOURCE CUT-OFF VOLTAGE vs.
CHANNEL TEMPERATURE



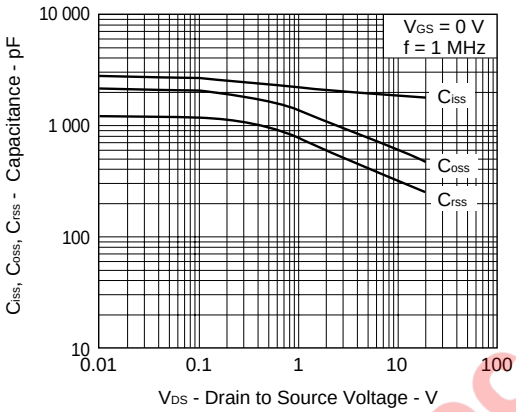
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



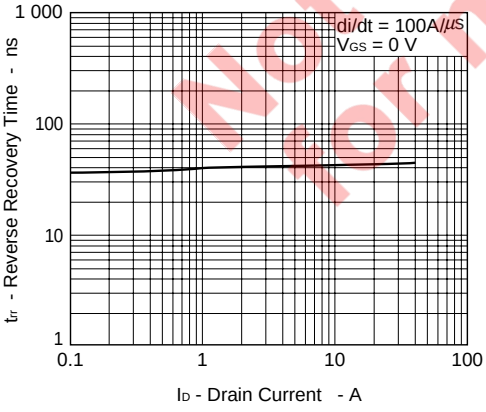
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



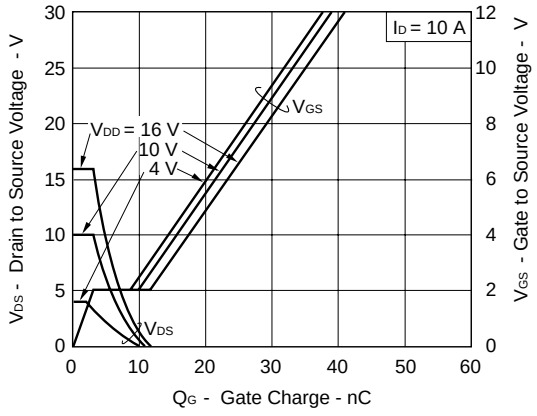
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



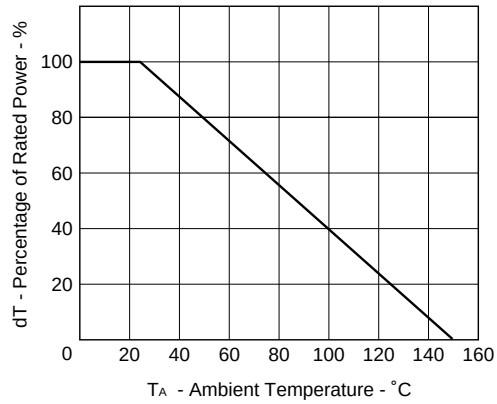
REVERSE RECOVERY TIME vs. DRAIN CURRENT



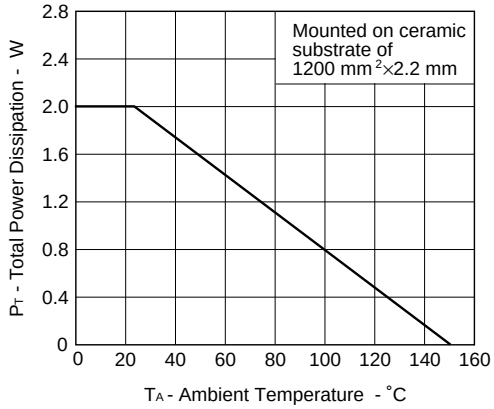
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



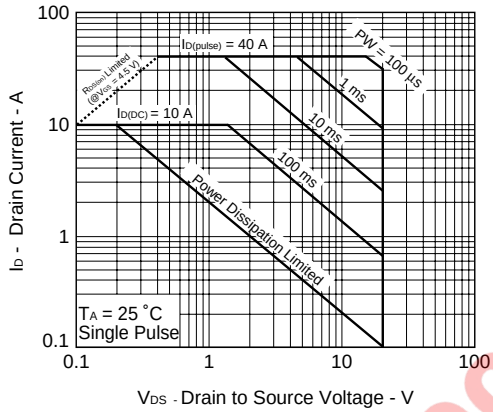
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

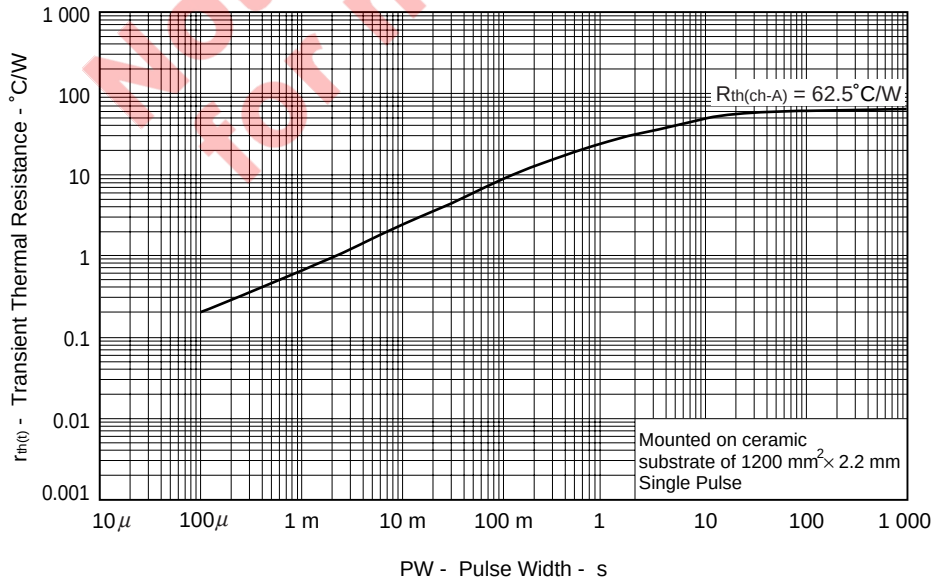


FORWARD BIAS SAFE OPERATING AREA



Remark
Mounted on ceramic substrate of 1200 mm^2 x 2.2 mm

TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



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